
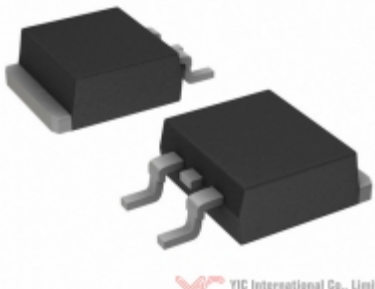








	<h2 style="color: red;">FQB4N20TM</h2>
	<p>Hersteller-Teilenummer: FQB4N20TM</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 200V 3.6A D2PAK</p> <p>Datenblätter:  FQB4N20TM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 32363 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB4N20TM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 200V 3.6A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	32363 pcs Stock
detaillierte Beschreibung	N-Channel 200V 3.6A (Tc) 3.13W (Ta), 45W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 45W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.6A (Tc)
Rds On (Max) @ Id, Vgs	1.4 Ohm @ 1.8A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6.5nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	220pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Cut Tape (CT)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FQB4N20TMCT































FQB4N20TM ist neu im Original, Suche FQB4N20TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB4N20TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB4N20TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB4N20TM Fairchild/ON Semiconductor MOSFET N-CH 200V 3.6A D2PAK</p>	 <p>FQB4N20 VB FQB4N20 VB</p>	 <p>FQB4N50 VB FQB4N50 VB</p>	 <p>FQB4N20TM VB FQB4N20TM VB</p>
 <p>FQB4N20L VB FQB4N20L VB</p>	 <p>FQB4N20LTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 3.8A D2PAK</p>	 <p>FQB4N50TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 3.4A D2PAK</p>	 <p>FQB4N25TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 3.6A D2PAK</p>

heiße Teile

Mehr

 FQB3N25TM	 FQB3N25TM	 FQB3N30TM	 FQB3N30TM	 FQB3N40TM
 FQB3N40TM	 FQB3N60C	 FQB3N80TM	 FQB3N80TM	 FQB3N90TM
 FQB3N90TM	 FQB3P20TM	 FQB3P20TM	 FQB3P50TM	 FQB3P50TM
 FQB44N10	 FQB44N10TM	 FQB44N10TM	 FQB46N15	 FQB46N15TM
 FQB47P06	 FQB47P06TM	 FQB4N20L	 FQB4N20LTM	 FQB4N20LTM
 FQB4N20TM	 FQB4N25TM	 FQB4N25TM	 FQB4N20TM	 FQB4N50TM
 FQB4N50TM	 FQB4N60C	 FQB4N80TM	 FQB4N80TM	 FQB4N90TM
 FQB4N90TM	 FQB4P25TM	 FQB4P25TM	 FQB50N03	 FQB50N06
 FQB50N06C	 FQB50N06L	 FQB50N06LTM	 FQB50N06LTM	 FQB50N06M
 FQB50N06TM	 FQB50N06TM	 FQB50N06TM-NL	 FQB55N06TM	 FQB55N06TM

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